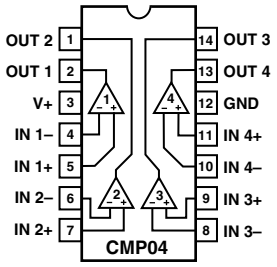
Quad Low Power, Precision Comparator

CMP04

FEATURES
- High Gain: 200 V/mV Typ
- Single- or Dual-Supply Operation
- Input Voltage Range Includes Ground
- Low Power Consumption (1.5 mW/Comparator)
- Low Input Bias Current: 100 nA Max
- Low Input Offset Current: 10 nA Max
- Low Offset Voltage: 1 mV Max
- Low Output Saturation Voltage: 250 mV @ 4 mA
- Logic Output Compatible with TTL, DTL, ECL, MOS, and CMOS
- Directly Replaces LM139/LM239/LM339 Comparators

PIN CONNECTIONS

14-Lead SOIC



GENERAL DESCRIPTION

Four precision independent comparators comprise the CMP04. Performance highlights include a very low offset voltage, low output saturation voltage, and high gain in a single-supply design. The input voltage range includes ground for single-supply operation and V– for split supplies. A low power supply current of 2 mA, which is independent of supply voltage, makes this the preferred comparator for precision applications requiring minimal power consumption. Maximum logic interface flexibility is offered by the open-collector TTL output.

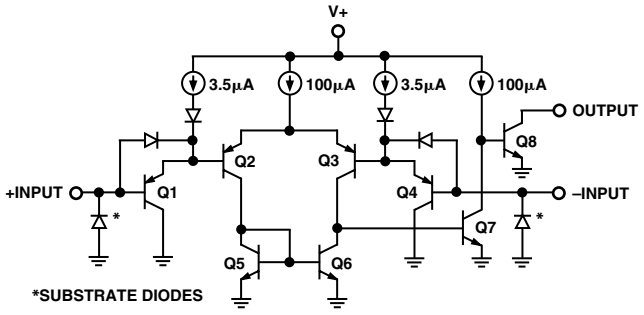


Figure 1. Simplified Schematic (1/4 CMP04)

TYPICAL INTERFACE

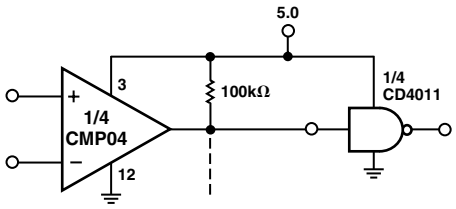


Figure 2a. Driving CMOS

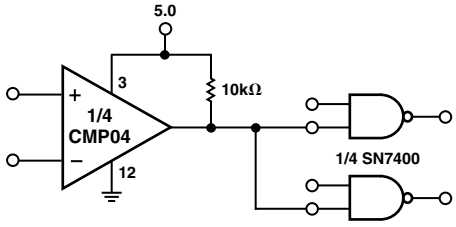


Figure 2b. Driving TTL

REV. D

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CMP04–SPECIFICATIONS

ELECTRICAL CHARACTERISTICS (@ V+ = 5 V, T_A = 25°C, unless otherwise noted.)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Input Offset Voltage	V_{OS}	R_S = 0 Ω, R_L = 5.1 kΩ, V_O = 1.4 V[1]		0.4	1	mV
Input Offset Current	I_{OS}	$I_{IN}(+) - I_{IN}(-)$, R_L = 5.1 kΩ, V_O = 1.4 V		2	10	nA
Input Bias Current	I_B	$I_{IN}(+)$ or $I_{IN}(-)$		25	100	nA
Voltage Gain	A_V	$R_L \geq 15$ kΩ, V+ = 15 V[2]	80	200		V/mV
Large Signal Response Time	t_r	V_{IN} = TTL Logic Swing, V_{REF} = 1.4 V[3]				
		V_{RL} = 5 V, R_L = 5.1 kΩ		300		ns
Small Signal Response Time	t_r	V_{IN} = 100 mV Step[3], 5 mV Overdrive				
		V_{RL} = 5 V, R_L = 5.1 kΩ		1.3		µs
Input Voltage Range	CMVR	Note 4	0		V+ – 1.5	V
Common-Mode Rejection Ratio	CMRR	Notes 2, 5	80	100		dB
Power Supply Rejection Ratio	PSRR	V+ = 5 V to 18 V[2]	80	100		dB
Saturation Voltage	V_{OL}	$V_{IN}(-) \geq 1$ V, $V_{IN}(+)$ = 0, $I_{SINK} \leq 4$ mA		250	400	mV
Output Sink Current	I_{SINK}	$V_{IN}(-) \geq 1$ V, $V_{IN}(+)$ = 0, $V_O \leq 1.5$ V	6	16		mA
Output Leakage Current	I_{LEAK}	$V_{IN}(+) \geq 1$ V, $V_{IN}(-)$ = 0, V_O = 30 V		0.1	100	nA
Supply Current	I+	$R_L = \infty$, All Comps V+ = 30 V		0.8	2.0	mA

NOTES
[1]At output switch point, V_O = 1.4 V, R_S = 0 Ω with V+ from 5 V, and over the full input common-mode range (0 V to V+ – 1.5 V).
[2]Guaranteed by design.
[3]Sample tested.
[4]The input common-mode voltage or input signal voltage should not be allowed to go negative by more than 0.3 V. The upper end of the common-mode voltage range is V+ – 1.5 V, but either or both inputs can go to 30 V without damage.
[5]$R_L \geq 15$ kΩ, V+ = 15 V, V_{CM} = 1.5 V to 13.5 V.

Specifications subject to change without notice.

ABSOLUTE MAXIMUM RATINGS[1]

Supply Voltage . . . . . +36 V or ±18 V
Differential Input Voltage . . . . . 36 V dc
Input Voltage . . . . . –0.3 V to +36 V
Operating Temperature Range
CMP04FS . . . . . –40°C to +85°C
Junction Temperature (T_J) . . . . . –65°C to +150°C
Storage Temperature Range . . . . . –65°C to +150°C
Input Current (V_{IN} < –3.0 V) . . . . . 50 mA
Output Short Circuit to GND . . . . . Continuous
Lead Temperature (Soldering, 60 sec) . . . . . 300°C

Package Type	θ_{JA}[2]	θ_{JC}	Unit
14-Lead SOIC	120	36	°C/W

NOTES
[1]Absolute maximum ratings apply to both DICE and packaged parts, unless otherwise noted. Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those listed in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.
[2]θ_{JA} is specified for worst-case mounting conditions, i.e., θ_{JA} is specified for device soldered to printed circuit board for SOIC package.

ORDERING GUIDE

Model	T_A = 25°C V_{OS}	Temperature Ranges	Package Descriptions	Package Options
CMP04FS	1 mV	–40°C to +85°C	14-Lead SOIC	R-14

CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although the CMP04 features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



ELECTRICAL CHARACTERISTICS (@ V+ = 5 V, –40°C ≤ T_A ≤ +85°C for CMP04FS, unless otherwise noted.)

Parameter	Symbol	Conditions	CMP04F[1] Min	Typ	Max	Unit
Input Offset Voltage	V_{OS}	R_S = 0 Ω, R_L = 5.1 kΩ		1	2	mV
		V_O = 1.4 V[2]		1	2	mV
Input Offset Current	I_{OS}	$I_{IN}(+) - I_{IN}(-)$		4	20	nA
		R_L = 5.1 kΩ		4	20	nA
		V_O = 1.4 V		4	20	nA
Input Bias Current	I_B	$I_{IN}(+)$ or $I_{IN}(-)$		40	200	nA
Voltage Gain	A_V	R_L ≥ 15 kΩ, V+ = 15 V[3]	70	125		V/mV
Large Signal Response Time	t_r	V_{IN} = TTL Logic Swing		300		ns
		V_{REF} = 1.4 V[4]		300		ns
		V_{RL} = 5 V, R_L = 5.1 kΩ		300		ns
Small Signal Response Time	t_r	V_{IN} = 100 mV Step[4]		1.3		µs
		5 mV Overdrive		1.3		µs
		V_{RL} = 5 V, R_L = 5.1 kΩ		1.3		µs
Input Voltage Range	CMVR	Note 5	0		V+ – 1.5	V
Common-Mode Rejection Ratio	CMRR	Notes 1, 3	60	100		dB
Power Supply Rejection Ratio	PSRR	V+ = 5 V to 18 V	80	100		dB
Saturation Voltage	V_{OL}	$V_{IN}(-)$ ≥ 1 V, $V_{IN}(+)$ = 0,		250	700	mV
		I_{SINK} ≤ 4 mA		250	700	mV
Output Sink Current	I_{SINK}	$V_{IN}(-)$ ≥ 1 V,	5	16		mA
		$V_{IN}(+)$ = 0, V_O ≤ 1.5 V	5	16		mA
Output Leakage Current	I_{LEAK}	$V_{IN}(+)$ ≥ 1 V,		0.1	200	nA
		$V_{IN}(-)$ = 0, V_O = 30 V		0.1	200	nA
Supply Current	I+	R_L = ∞, All Comps		1.2	3.0	mA
		V+ = 30 V		1.2	3.0	mA

NOTES
[1]R_L ≥ 15 kΩ, V+ = 15 V, V_{CM} = 1.5 V to 13.5 V.
[2]At output switch point, V_O = 1.4 V, R_S = 0 Ω with V+ from 5 V; and over the full input common-mode range (0 V to V+ –1.5 V).
[3]Guaranteed by design.
[4]Sample tested.
[5]The input common-mode voltage or input signal voltage should not be allowed to go negative by more than 0.3 V. The upper end of the common-mode voltage range is V+ – 1.5 V, but either or both inputs can go to +30 V without damage.

Specifications subject to change without notice.

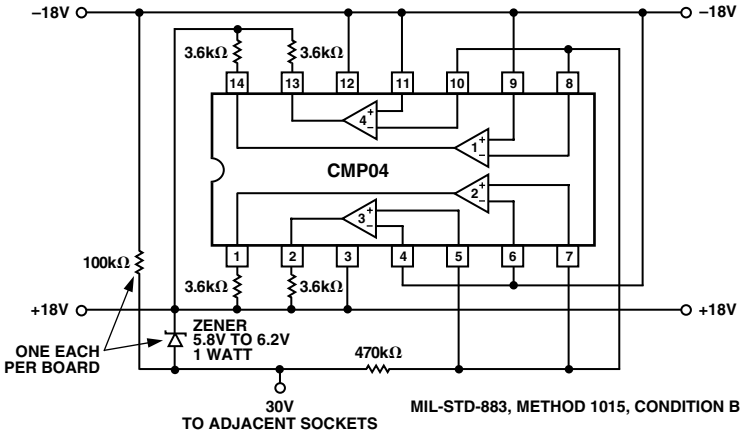
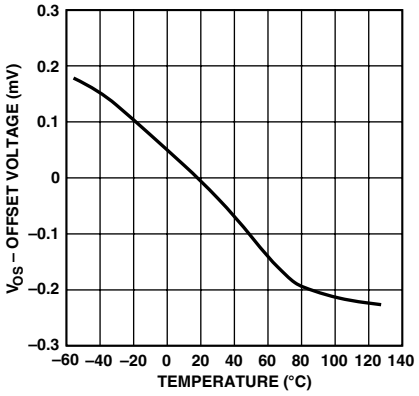
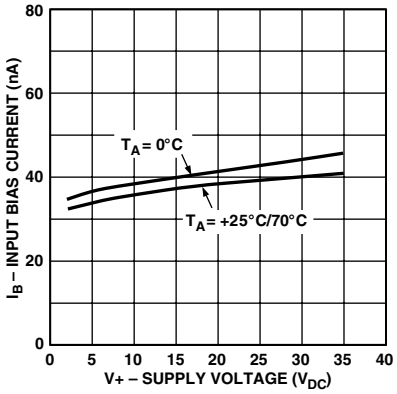


Figure 3. Burn-In Circuit

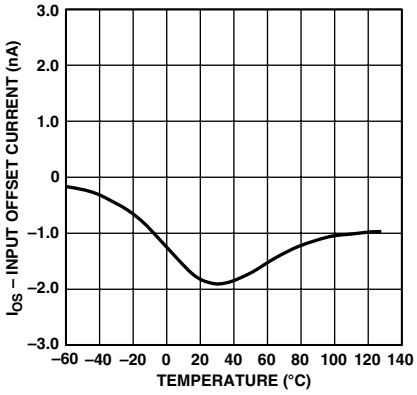
CMP04–Typical Performance Characteristics



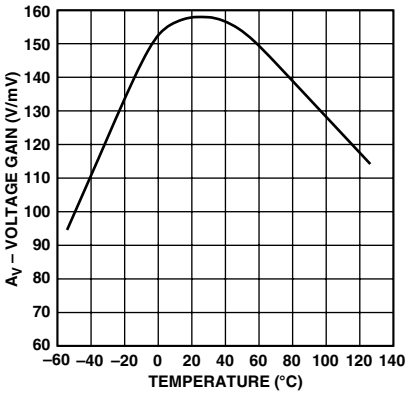
TPC 1. Offset Voltage vs. Temperature



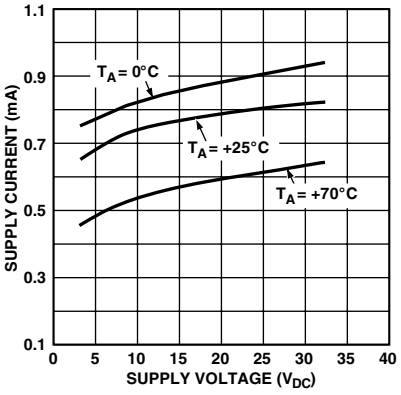
TPC 2. Input Bias Current vs. V+ and Temperature



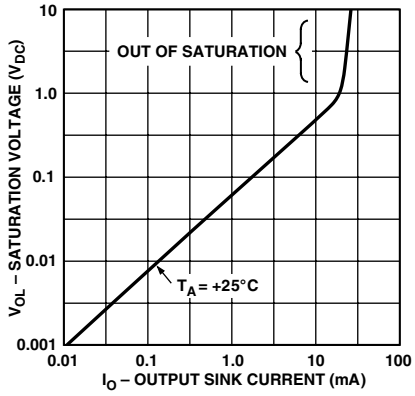
TPC 3. Input Offset Current vs. Temperature



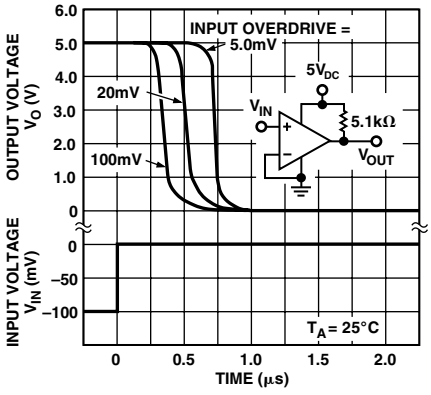
TPC 4. Voltage Gain vs. Temperature



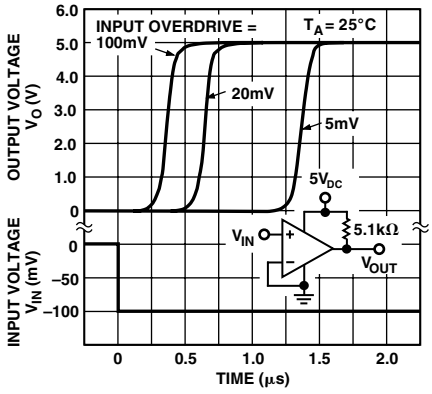
TPC 5. Supply Current vs. Supply Voltage



TPC 6. Output Voltage vs. Output Current and Temperature



TPC 7. Response Time for Various Input Overdrives—Negative Transition



TPC 8. Response Time for Various Input Overdrives—Positive Transition

TYPICAL APPLICATIONS

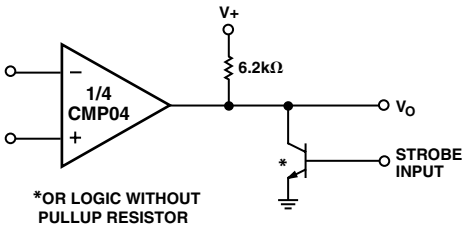


Figure 4. Output Strobing

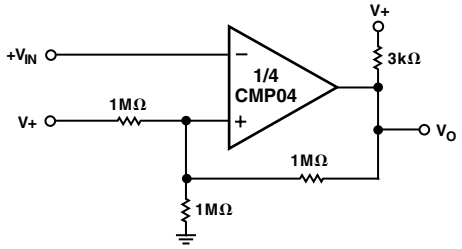


Figure 7. Inverting Comparator with Hysteresis

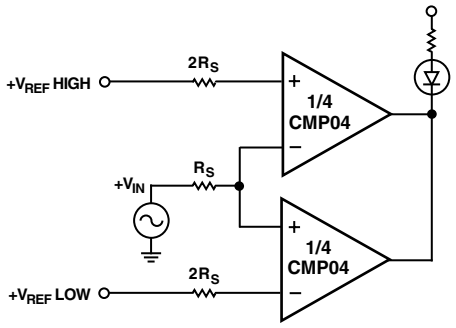


Figure 5. Limit Comparator

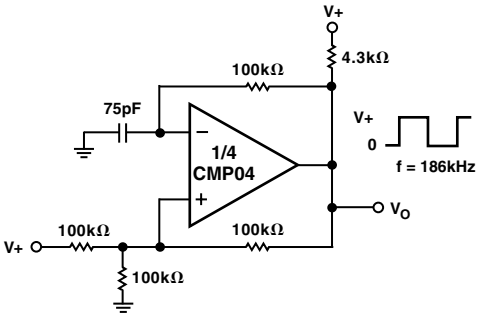


Figure 8. Square Wave Oscillator

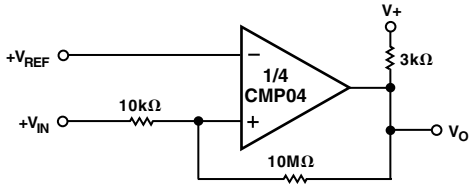


Figure 6. Noninverting Comparator with Hysteresis

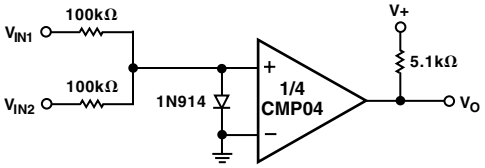


Figure 9. Comparing Input Voltages of Opposite Polarity

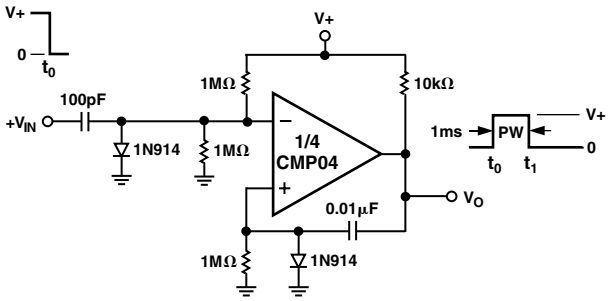


Figure 10. One-Shot Multivibrator

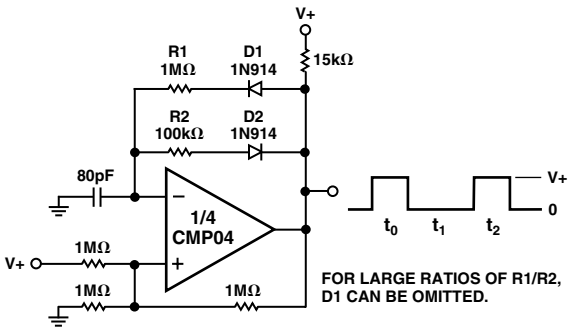


Figure 12. Pulse Generator

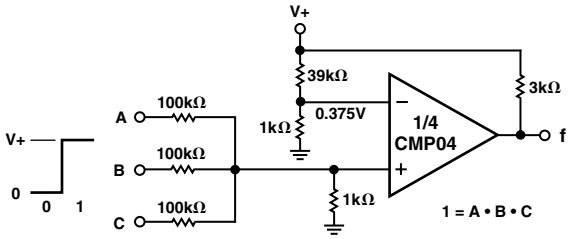


Figure 11. AND Gate

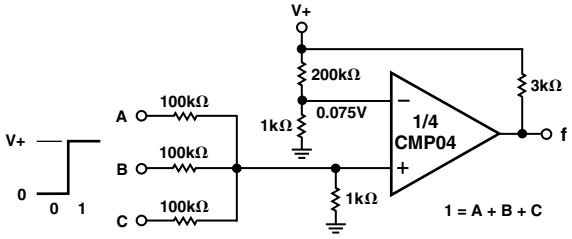


Figure 13. OR Gate

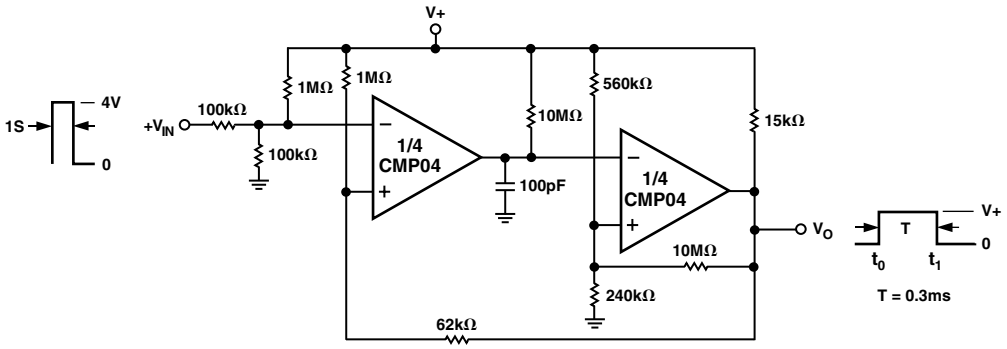


Figure 14. One-Shot Multivibrator with Input Lockout

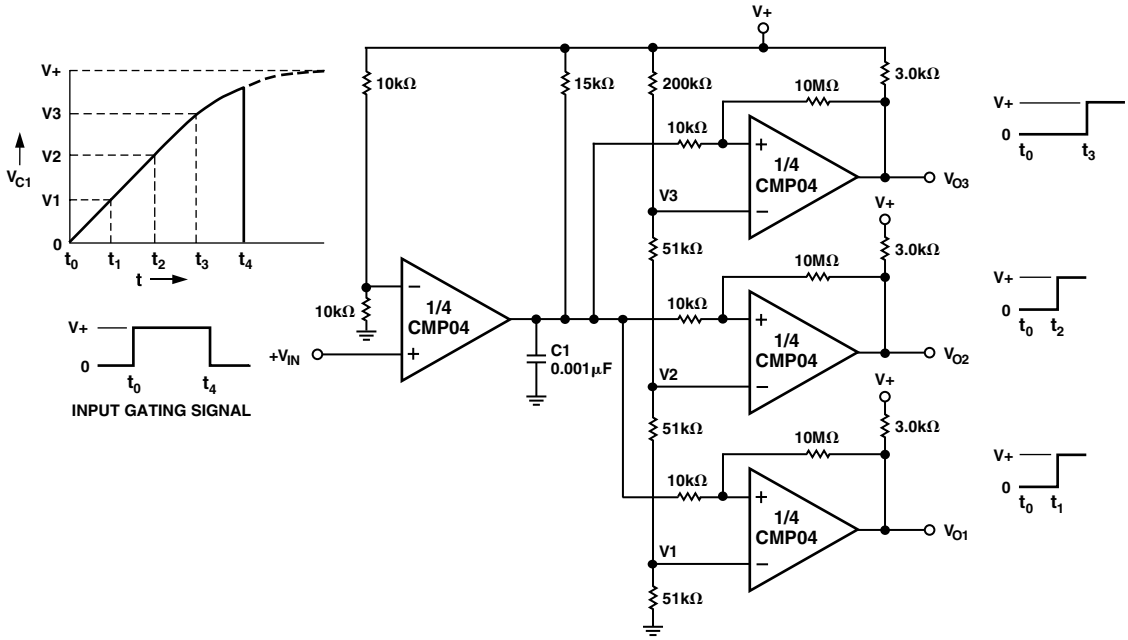
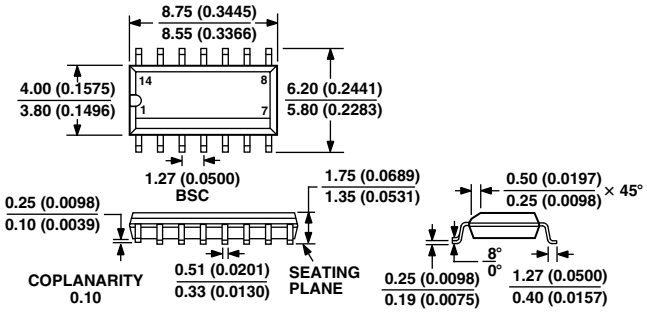


Figure 15. Time Delay Generator

OUTLINE DIMENSIONS

14-Lead Standard Small Outline Package [SOIC]
Narrow Body
(R-14)

Dimensions shown in millimeters and (inches)



COMPLIANT TO JEDEC STANDARDS MS-012AB
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS
(IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR
REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN

C00266–0–3/03(D)

Revision History

Location	Page
3/03—Data Sheet changed from REV. C to REV. D.	
Renumbered TPCs and Figures	Global
Deletion of 14-Lead CERDIP and 14-Lead PDIP information	Global
Changes to FEATURES	1
Changes to PIN CONNECTIONS	1
Changes to ABSOLUTE MAXIMUM RATINGS	2
Changes to ORDERING GUIDE	2
Changes to ELECTRICAL CHARACTERISTICS	3
Removal of DICE CHARACTERISTICS, WAFER TEST LIMITS, and TYPICAL ELECTRICAL CHARACTERISTICS sections	4
Changes to TPCs 2, 5, and 6	4
Updated OUTLINE DIMENSIONS	8

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